82**Kr(p,p') IAR** 1969**Ki14**

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1969Ki14: E(p)=3.7 to 5.4 MeV. Measured $\sigma(\theta)$, excitation function using Si surface barrier detectors.

The first excited state $(J^{\pi}=2^{+})$ was observed to resonate at a bombarding energy of 5.34 MeV, indicating the presence of an analog state in 83 Rb. Assuming this resonance is a manifestation of an analog of a low-lying state of 83 Kr, the corresponding state in 83 Kr would have an excitation energy of 1.89 MeV *I*. No resonance was observed for the yield to the 1470-keV, second excited state in 82 Kr.